Application No.: 10/538,689

Art Unit: 2814

Attorney Docket No.: 052684

AMENDMENTS TO THE CLAIMS

Listing of claims:

This listing of claims replaces all prior versions and listings of claims in the application.

Claim 1 (Previously Presented): A spin injection device comprising:

a spin injection part having a spin polarizing part consisting of a ferromagnetic layer and

an injection junction part consisting of a nonmagnetic insulating layer; and

SyAF having a first magnetic layer and a second magnetic layer having different

magnitudes of magnetization, and magnetically coupled together antiparallel to each other via a

nonmagnetic layer, wherein said first magnetic layer of SyAF and said injection junction part are

bonded, and

a spin polarization electron is injected from said spin injection part by flowing electric

current between said spin polarizing part and said second magnetic layer, wherein magnetization

of said first and second magnetic layers is reversed while maintained in antiparallel state without

applying an external magnetic field, and wherein

said flowing electric current is 1 mA or less.

Claim 2 (canceled)

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Claim 3 (Previously Presented): The spin injection device as set forth in claim 1,

wherein said spin polarization electron is capable of spin conservation conduction or tunnel

junction at the injection junction part of said spin injection part.

Claim 4 (canceled)

Claim 5 (Previously Presented): The spin injection device as set forth in claim 1 or claim

3, wherein the ferromagnetic layer is provided in contact with an antiferromagnetic layer that

fixes the spin of said ferromagnetic layer.

Claim 6 (Currently Amended): The spin injection device as set forth in claim 1 or claim

3, wherein the aspect ratio of the first and the second magnetic layers of SyAF in contact with the

injection junction part of said spin injection parts is less than 2.

Claim 7 (Previously Presented): A spin injection magnetic apparatus comprising:

a spin injection part having a spin polarizing part consisting of a first ferromagnetic layer

and an injection junction part consisting of a first insulating layer, said first insulating layer

formed in contact with said first ferromagnetic layer;

an SyAF free layer formed in contact with said first insulating layer, said SyAF free layer

having a first magnetic layer and a second magnetic layer coupled together magnetically

antiparallel to each other via a nonmagnetic layer, and in which magnitudes of magnetization are

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different, and the magnetization of said first magnetic layer and said second magnetic layer is

capable of magnetization reversal while maintaining the antiparallel state; and

a ferromagnetic fixed layer tunnel-junctioned with the first magnetic layer of said SyAF

free layer via a second insulating layer, wherein:

said ferromagnetic fixed layer and said free layer are made to be a ferromagnetic spin

tunnel junction, and

the magnetization of said first and second magnetic layers is reversed by flowing electric

current between said second magnetic layer of the free layer and said ferromagnetic fixed layer

while maintained in an antiparallel state without applying an external magnetic field, and

wherein said flowing electric current is 1 mA or less.

Claims 8 and 9 (canceled)

Claim 10 (Previously Presented): The spin injection magnetic apparatus as set forth in

claim 7, wherein a spin polarization electron is capable of spin conservation conduction or tunnel

junction at the injection junction part of said spin injection part.

Claim 11 (canceled)

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Claim 12 (Previously Presented): The spin injection magnetic apparatus as set forth in

claim 7, wherein the spin polarization part of said spin injection part is provided in contact with

an antiferromagnetic layer that fixes the spin of a ferromagnetic layer.

Claim 13 (Previously Presented): The spin injection magnetic apparatus as set forth in

claim 7, wherein the aspect ratio of the first and the second magnetic layers of the free layer in

contact with the injection junction part of said spin injection part is less than 2.

Claim 14 (Previously Presented): The spin injection magnetic apparatus as set forth in

claim 7, wherein said spin injection part is word line.

Claim 15 (Previously Presented): A spin injection device comprising:

a spin injection part having a spin polarization part including a ferromagnetic fixed layer

and an injection junction part of a nonmagnetic layer, said nonmagnetic layer formed contacted

with said ferromagnetic fixed layer;

a ferromagnetic free layer provided in contact with said injection junction part; and

an antinonferromagnetic layer provided on the surface of said ferromagnetic free layer,

wherein:

said nonmagnetic layer of the injection junction part is made of an insulator or a

conductor, and

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the magnetization of said ferromagnetic free layer by flowing electric current between the

spin polarization part and said nonmagnetic layer provided on the surface of said ferromagnetic

free layer in the direction perpendicular to the film surface without applying an external magnetic

field, and wherein said flowing electric current is 1 mA or less.

Claim 16 (Previously Presented): The spin injection device as set forth in claim 15,

wherein said ferromagnetic free layer is made of Co or Co alloy, said antinonferromagnetic layer

provided on the surface of said ferromagnetic free layer is any one of Ru, Ir and Rh layer, and its

film thickness is 0.1 nm - 20 nm.

Claim 17 (Previously Presented): A spin injection device comprising:

a spin injection part having a spin polarization part including a first ferromagnetic fixed

layer and an injection junction part of a nonmagnetic layer, said nonmagnetic layer formed in

contact with said ferromagnetic fixed layer;

a ferromagnetic free layer provided in contact with said injection junction part; and

a antinonferromagnetic layer formed in contact with said ferromagnetic free layer; and

a second ferromagnetic fixed layer provided on the surface of said antinonferromagnetic

layer, wherein:

said nonmagnetic layer of the injection junction part is made of an insulator or a

conductor,

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the magnetization of said ferromagnetic free layer is reversed by flowing electric current

between the spin polarization part and the second ferromagnetic fixed layer provided on the

surface of said ferromagnetic free layer in the direction perpendicular to the film surface without

applying external magnetic field, and wherein said flowing electric current is 1 mA or less.

Claim 18 (Previously Presented): The spin injection device as set forth in claim 17,

wherein said ferromagnetic free layer and said first and second ferromagnetic layer are made of

Co or Co alloy, an antinonferromagnetic layer provided on the surface of said ferromagnetic free

layer is any one of Ru, Ir and Rh layer, and its film thickness is 2 nm - 20 nm.

Claim 19 (Previously Presented): A spin injection magnetic apparatus wherein, said spin

injection apparatus uses the spin injection device as set forth in any one of said claims 15 - 18.

Claim 20 (Previously Presented): A spin injection magnetic memory device, wherein the

spin injection magnetic memory device uses the spin injection device as set forth in any one of

said claims 15 - 18.

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Claims 21-50 (Canceled)

Claim 51 (Previously Presented): A spin injection device comprising:

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a spin injection part having a spin polarizing part consisting of a ferromagnetic layer and

an injection junction part consisting of a nonmagnetic conductive layer, and SyAF having a first

magnetic layer and a second magnetic layer having different magnitudes of magnetization and

magnetically coupled together antiparallel to each other via a nonmagnetic layer, wherein said

first layer of SyAF and said injection junction part are bonded and

a spin polarization electron is injected from said spin injection part by flowing electric

current between said a spin polarizing part and the second magnetic layer, wherein magnetization

of said first and second magnetic layers is reversed while maintained in an antiparallel state

without applying a external magnetic field, and wherein said flowing electric current is 1mA or

less.

Claim 52 (Currently Amended): The spin injection device as set forth in claim [[21]] 51,

wherein said spin polarization electron is capable of spin conservation conduction at the

injection junction part of said spin injection part.

Claim 53 (Currently Amended): The spin injection device as set forth in claim [[21]] 51

or claim [[22]] 52, wherein the ferromagnetic layer is provided in contact with an

antiferromagnetic layer that fixes the spin of a ferromagnetic layer.

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Claim 54 (Currently Amended): The spin injection device as set forth in claim [[21]] 51 or claim [[22]] 52, wherein the aspect ratio of the first and the second magnetic layers of SyAF in contact with the injection junction part of said spin injection parts is less than 2.